

Features

- High Speed Smooth Switching Device for Hard & Soft Switching
- Positive Temperature Coefficient
- High Ruggedness ,Temperature Stable
- Maximum junction temperature 175 °C
- Halogen Free. "Green" Device (Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant (Note 2)("P" Suffix Designates RoHS Compliant. See Ordering Information)

Applications

- General purpose inverters
- Motor drives
- Uninterruptible power supply
- Medium to low switching frequency power converters

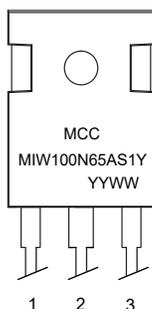
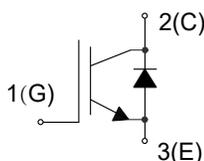
Maximum Ratings

| Parameter | Symbol | Rating | Unit |
|---|---------------|--------------------|--------------|
| Collector-Emitter Voltage | V_{CE} | 650 | V |
| DC Collector Current (Note 3) | I_C | $T_C=25^{\circ}C$ | 160 (Note 4) |
| | | $T_C=100^{\circ}C$ | 100 |
| Pulsed Collector Current, $V_{GE}=15V$ (Note 5) | $I_{C,pluse}$ | 400 | A |
| Diode Forward Current (Note 3) | I_F | $T_C=25^{\circ}C$ | 160 (Note 4) |
| | | $T_C=100^{\circ}C$ | 100 |
| Diode Pulsed Current (Note 5) | $I_{F,pluse}$ | 400 | A |
| Gate-Emitter Voltage | V_{GE} | ± 20 | V |
| Transient Gate-Emitter Voltage (Note 6) | | ± 30 | |
| Power Dissipation | P_D | $T_C=25^{\circ}C$ | 535 |
| | | $T_C=100^{\circ}C$ | 267.5 |

Note:

1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
2. High Temperature Solder Exemptions Applied, see EU Directive Annex 7a.
3. Limited by T_{Jmax} .
4. Value limited by bondwire.
5. T_p limited by T_{Jmax} .
6. $T_p \leq 10\mu s$, Duty Cycle < 1%.

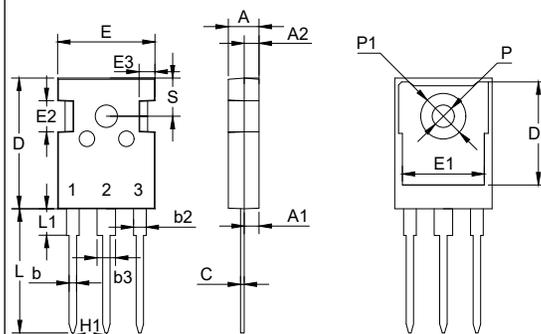
Internal Structure



Device Code: MIW100N65AS1Y
Date Code: YYWW (Year & Week)

Trench and Field Stop IGBT 650V 100A

TO-247AB



DIMENSIONS

| DIM | INCHES | | MM | | NOTE |
|-----|--------|-------|-------|-------|------|
| | MIN | MAX | MIN | MAX | |
| A | 0.189 | 0.205 | 4.80 | 5.20 | |
| A1 | 0.087 | 0.103 | 2.21 | 2.61 | |
| A2 | 0.073 | 0.085 | 1.85 | 2.15 | |
| b | 0.039 | 0.055 | 1.00 | 1.40 | |
| b2 | 0.075 | 0.087 | 1.91 | 2.21 | |
| C | 0.020 | 0.028 | 0.50 | 0.70 | |
| D | 0.815 | 0.839 | 20.70 | 21.30 | |
| D1 | 0.640 | 0.663 | 16.25 | 16.85 | |
| E | 0.610 | 0.634 | 15.50 | 16.10 | |
| E1 | 0.512 | 0.535 | 13.00 | 13.60 | |
| E2 | 0.189 | 0.205 | 4.80 | 5.20 | |
| E3 | 0.091 | 0.106 | 2.30 | 2.70 | |
| L | 0.772 | 0.796 | 19.62 | 20.22 | |
| L1 | - | 0.169 | - | 4.30 | |
| P | 0.134 | 0.150 | 3.40 | 3.80 | Φ |
| P1 | | 0.287 | - | 7.30 | Φ |
| S | 0.242 | | 6.15 | | TYP |
| H1 | 0.214 | | 5.44 | | TYP |
| b3 | 0.110 | 0.126 | 2.80 | 3.20 | |

Electrical Characteristics of the IGBT @ T_J=25°C (Unless Otherwise Specified)

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Unit | |
|---------------------------------------|----------------------|--|--|------|------|------|----|
| IGBT Static Characteristics | | | | | | | |
| Collector-Emitter Breakdown Voltage | V _{(BR)CES} | V _{GE} =0V, I _C =250μA | 650 | | | V | |
| Collector-Emitter Saturation Voltage | V _{CE(sat)} | V _{GE} =15V, I _C =100A, T _J =25°C | 1.20 | 1.50 | 1.80 | V | |
| | | V _{GE} =15V, I _C =100A, T _J =125°C | | 1.70 | | | |
| | | V _{GE} =15V, I _C =100A, T _J =150°C | | 1.80 | | | |
| G-E Threshold Voltage | V _{GE(th)} | I _C =1mA, V _{CE} =V _{GE} | 3.30 | 4.10 | 4.90 | V | |
| C-E Leakage Current | I _{CES} | V _{CE} =650V, V _{GE} =0V, T _J =25°C | | | 0.25 | mA | |
| | | V _{CE} =650V, V _{GE} =0V, T _J =150°C | | | 3 | | |
| G-E Leakage Current | I _{GES} | V _{CE} =0V, V _{GE} =±20V | | | 200 | nA | |
| Dynamic Characteristics | | | | | | | |
| Input Capacitance | C _{ies} | V _{CE} =25V, V _{GE} =0V, f=1MHz | | 4.96 | | nF | |
| Reverse Transfer Capacitance | C _{res} | | | 0.05 | | | |
| Gate Charge | Q _g | V _{CC} =300V, I _C =100A, V _{GE} =-5V~+15V | | 0.34 | | μC | |
| IGBT Switching Characteristics | | | | | | | |
| Turn-On Delay Time | td _(on) | V _{CC} =300V, I _C =100A, V _{GE} =-5V~15V, R _G =10Ω, T _J =25°C Inductive Load | | 19 | | ns | |
| Rise Time | t _r | | | 95 | | | |
| Turn-Off Delay Time | td _(off) | | | 204 | | | |
| Fall Time | t _f | | | 44 | | | |
| Turn-On Energy | E _{on} | | | | 4.0 | | mJ |
| Turn-Off Energy | E _{off} | | | | 1.1 | | |
| Turn-On Delay Time | td _(on) | | V _{CC} =300V, I _C =100A, V _{GE} =-5V~15V, R _G =10Ω, T _J =125°C Inductive Load | | 22 | | ns |
| Rise Time | t _r | | | | 88 | | |
| Turn-Off Delay Time | td _(off) | | | | 220 | | |
| Fall Time | t _f | | | | 55 | | |
| Turn-On Energy | E _{on} | | | | 4.1 | | mJ |
| Turn-Off Energy | E _{off} | | | | 1.4 | | |
| Turn-On Delay Time | td _(on) | V _{CC} =300V, I _C =100A, V _{GE} =-5V~15V, R _G =10Ω, T _J =150°C Inductive Load | | | 23 | | ns |
| Rise Time | t _r | | | | 84 | | |
| Turn-Off Delay Time | td _(off) | | | | 226 | | |
| Fall Time | t _f | | | | 59 | | |
| Turn-On Energy | E _{on} | | | | 4.2 | | mJ |
| Turn-Off Energy | E _{off} | | | | 1.6 | | |

Electrical Characteristics of the Diode @ $T_J=25^\circ\text{C}$ (Unless Otherwise Specified)

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Unit |
|------------------------------|-----------|--|-----|------|------|---------------|
| Diode Characteristics | | | | | | |
| Diode Forward Voltage | V_F | $V_{GE}=0\text{V}, I_F=100\text{A}, T_J=25^\circ\text{C}$ | | 1.40 | 1.90 | V |
| | | $V_{GE}=0\text{V}, I_F=100\text{A}, T_J=125^\circ\text{C}$ | | 1.35 | | |
| | | $V_{GE}=0\text{V}, I_F=100\text{A}, T_J=150^\circ\text{C}$ | | 1.30 | | |
| Reverse Recovery Current | I_{rr} | $V_R=300\text{V}, I_F=100\text{A},$ $di_F/dt=-550\text{A}/\mu\text{s}, T_J=25^\circ\text{C}$ | | 23 | | A |
| Diode Reverse Recovery Time | t_{rr} | | | 116 | | ns |
| Reverse Recovery Charge | Q_{rr} | | | 1.8 | | μC |
| Reverse Recovery Energy | E_{rec} | | | 0.16 | | mJ |
| Reverse Recovery Current | I_{rr} | $V_R=300\text{V}, I_F=100\text{A},$ $di_F/dt=-550\text{A}/\mu\text{s}, T_J=125^\circ\text{C}$ | | 36 | | A |
| Diode Reverse Recovery Time | t_{rr} | | | 158 | | ns |
| Reverse Recovery Charge | Q_{rr} | | | 4.2 | | μC |
| Reverse Recovery Energy | E_{rec} | | | 0.47 | | mJ |
| Reverse Recovery Current | I_{rr} | $V_R=300\text{V}, I_F=100\text{A},$ $di_F/dt=-550\text{A}/\mu\text{s}, T_J=150^\circ\text{C}$ | | 41 | | A |
| Diode Reverse Recovery Time | t_{rr} | | | 197 | | ns |
| Reverse Recovery Charge | Q_{rr} | | | 5.7 | | μC |
| Reverse Recovery Energy | E_{rec} | | | 0.61 | | mJ |

Thermal characteristics

| Parameter | Symbol | Min | Typ | Max | Units |
|--|----------------|-----|-----|------|---------------------------|
| Operating Junction Temperature Range | T_J | -40 | | 175 | $^\circ\text{C}$ |
| Storage Temperature Range | T_{stg} | -55 | | 150 | $^\circ\text{C}$ |
| Thermal Resistance from Junction to Case (IGBT) | $R_{th_{J-C}}$ | | | 0.28 | $^\circ\text{C}/\text{W}$ |
| Thermal Resistance from Junction to Case (Diode) | $R_{th_{J-C}}$ | | | 0.45 | $^\circ\text{C}/\text{W}$ |
| Thermal Resistance from Junction to Ambient | $R_{th_{J-A}}$ | | | 40 | $^\circ\text{C}/\text{W}$ |

Curve Characteristics

Fig. 1 - Typical Output Characteristic ($T_j=25^\circ\text{C}$)

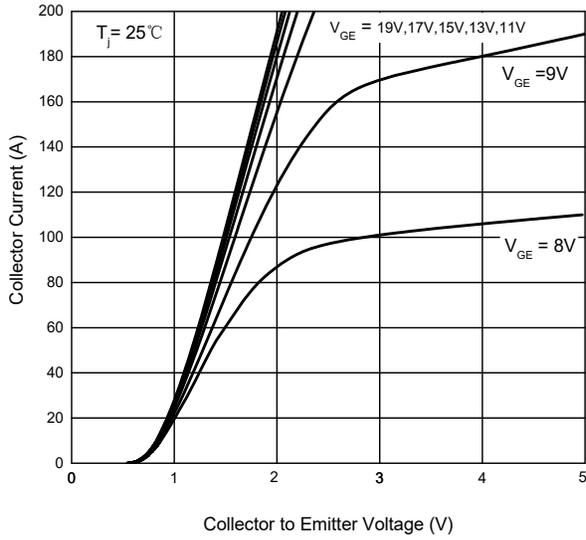


Fig. 2 - Typical Output Characteristic ($T_j=150^\circ\text{C}$)

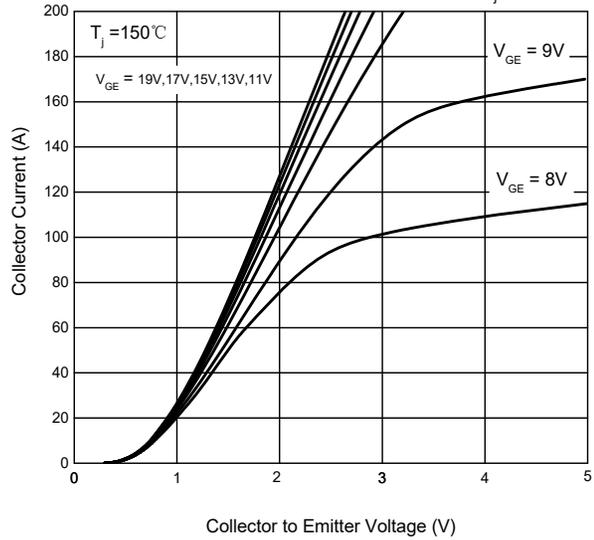


Fig. 3 - Typical Transfer Characteristic

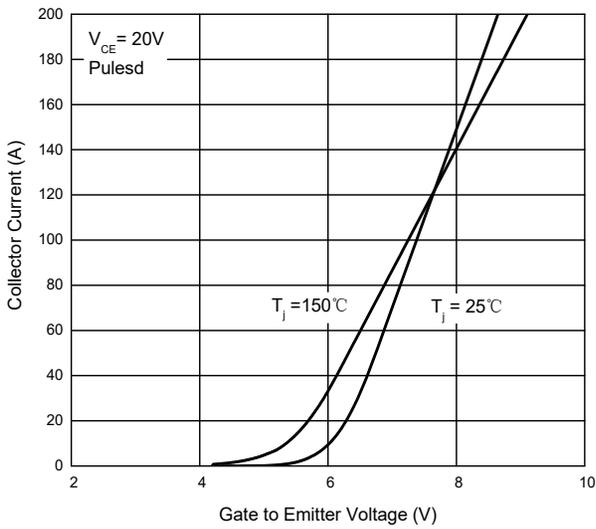


Fig. 4 - Diode Forward Current vs. Forward Voltage

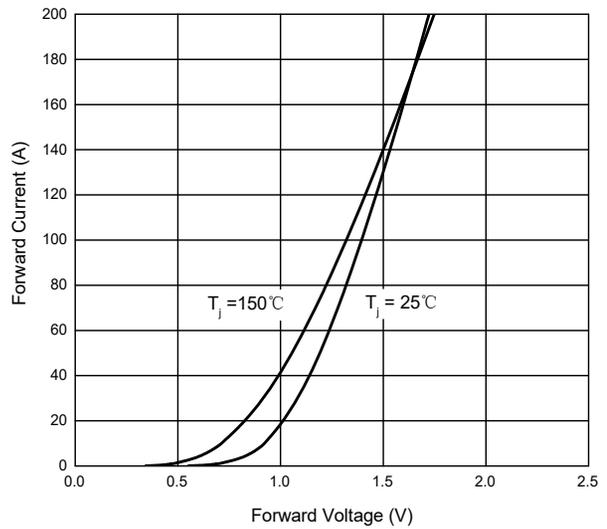


Fig. 5 - Diode VF vs. Junction Temperature

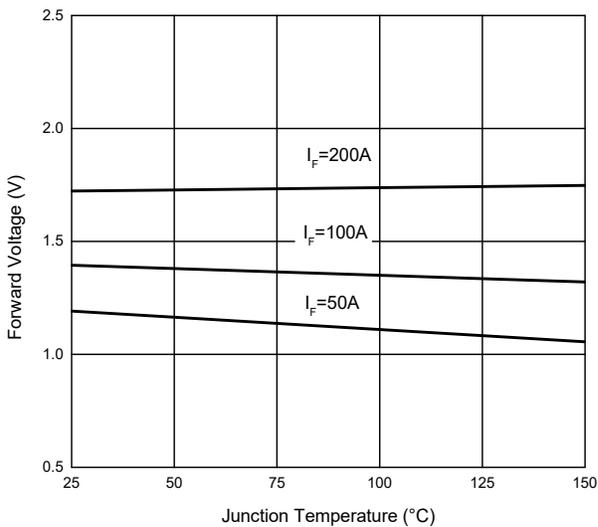
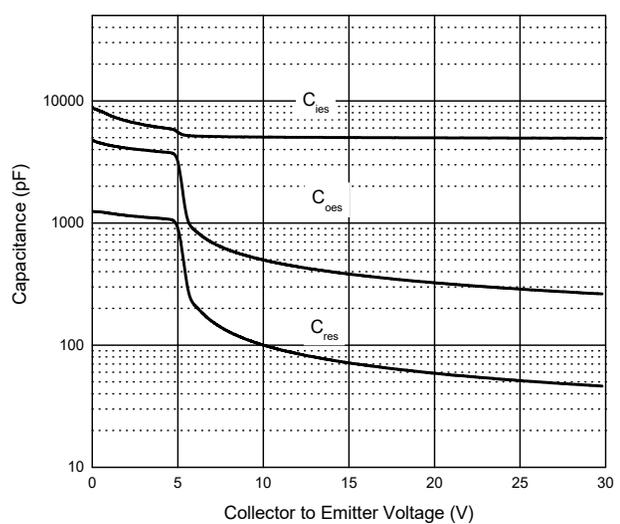


Fig. 6 - Capacitance Characteristics



Curve Characteristics

Fig. 7 - IGBT Switching Loss vs. I_c

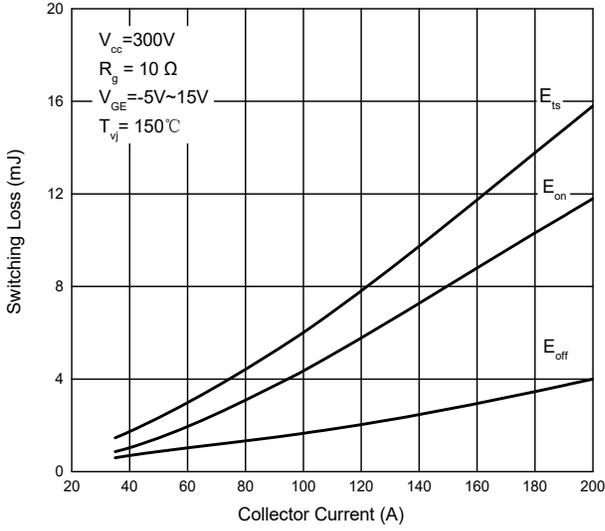


Fig. 8- IGBT Switching Loss vs. R_g

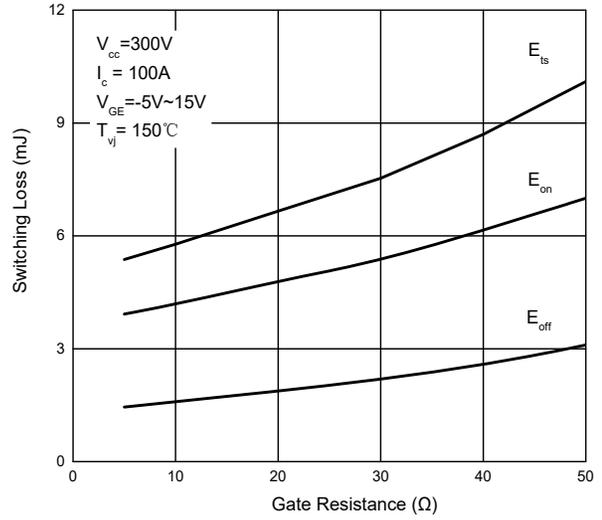


Fig. 9 -IGBT Switching Loss vs. Junction Temperature

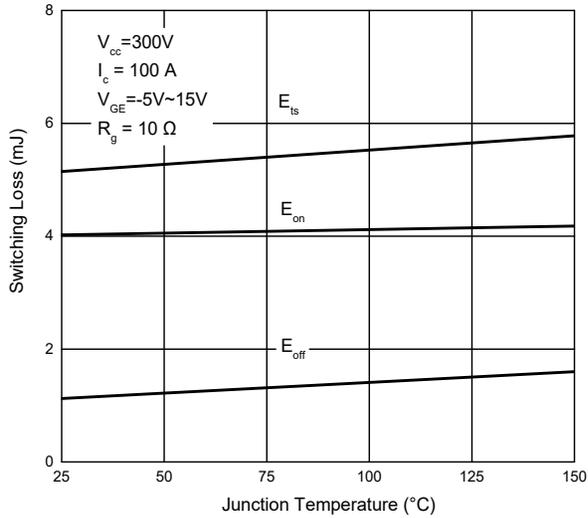


Fig. 10 - Switching Loss vs. V_{CE}

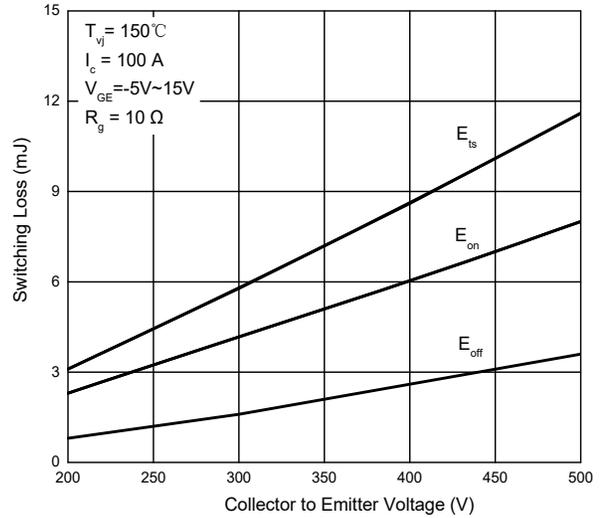


Fig. 11 - $V_{CE(sat)}$ vs. Junction Temperature

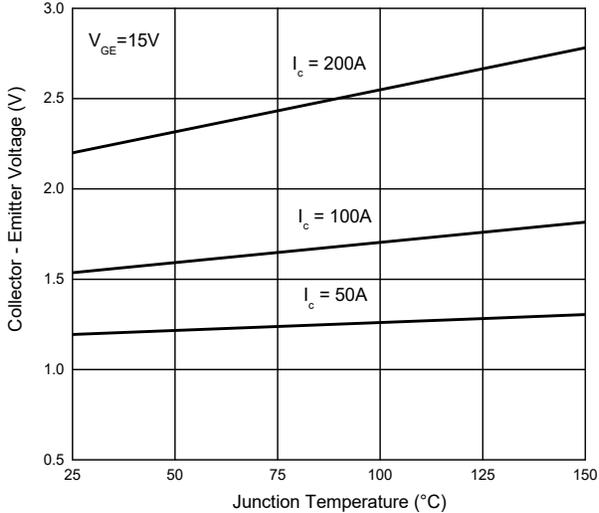
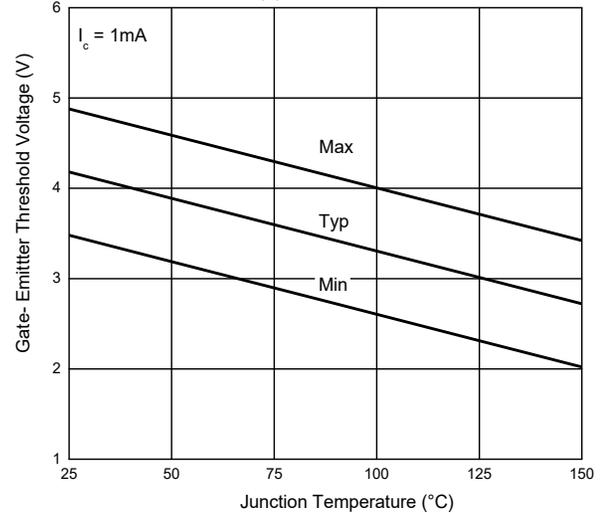


Fig. 12- $V_{GE(th)}$ vs. Junction Temperature



Curve Characteristics

Fig. 13 - Switching Times vs. Collect Current

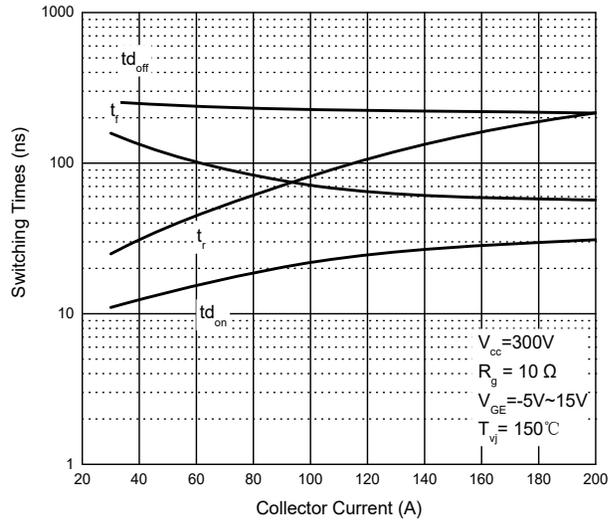


Fig. 14 - Switching Times vs. Gate Resistance

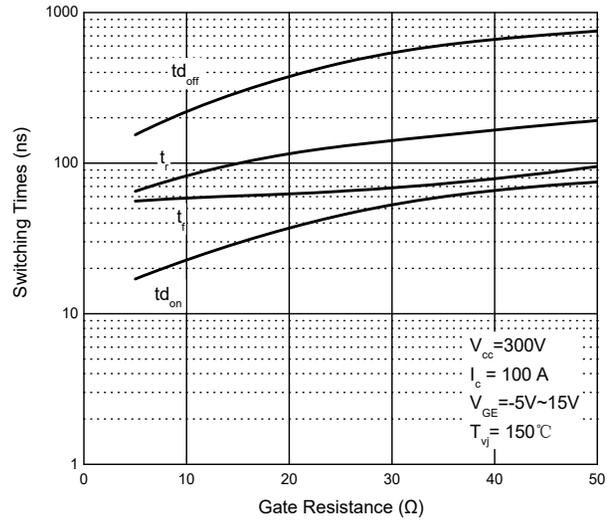


Fig. 15 - IGBT Transient Thermal Impedance

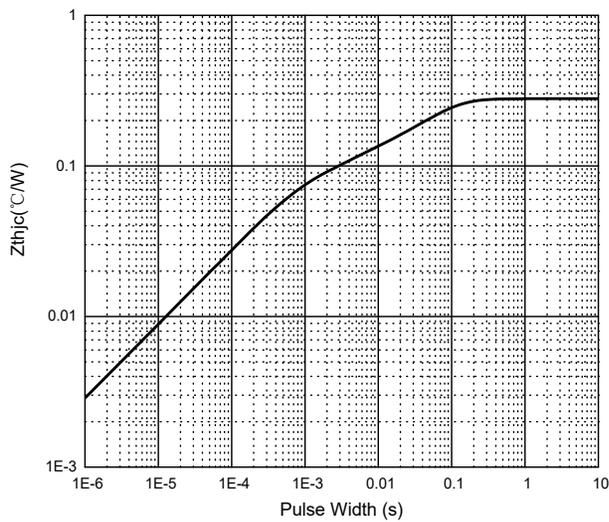


Fig. 16 - Diode Transient Thermal Impedance

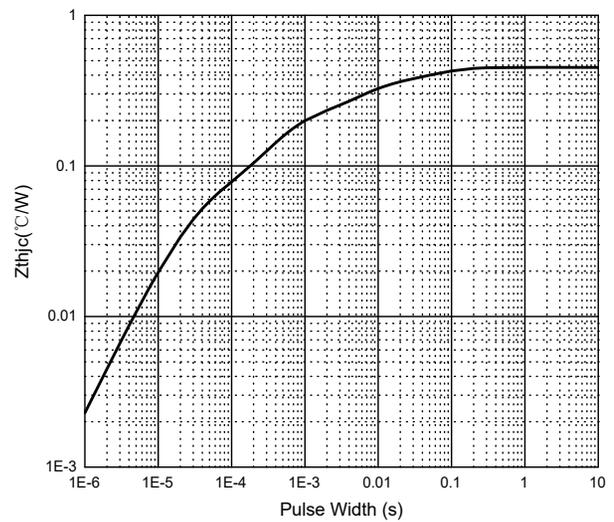


Fig. 17 - Collector Current vs. Case Temperature

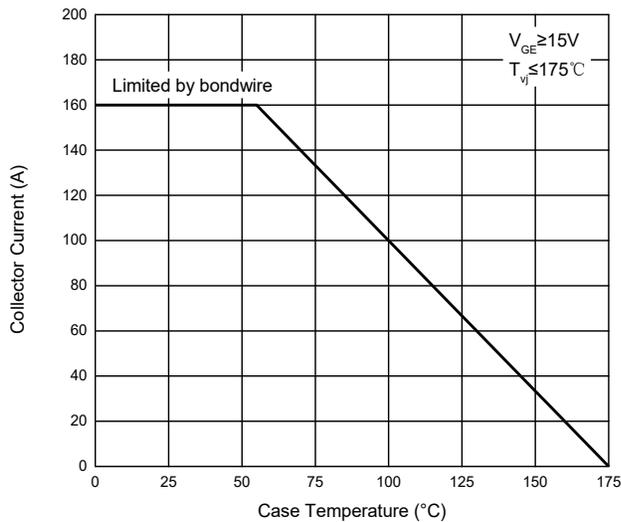
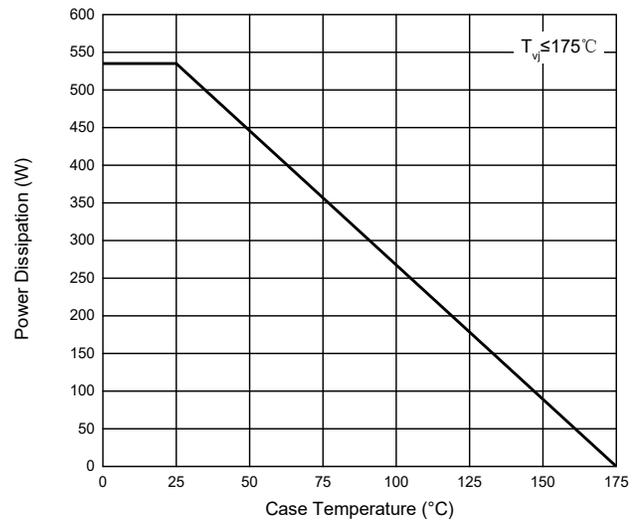
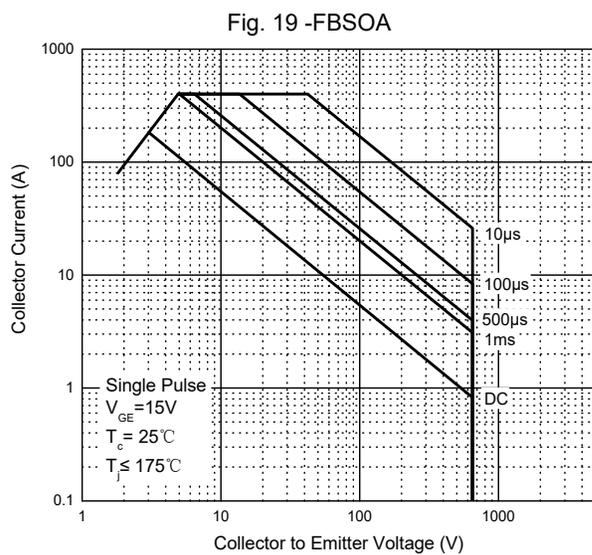


Fig. 18 - Power Derating



Curve Characteristics



Ordering Information

| Device | Packing |
|----------------|-------------------------------|
| Part Number-BP | Tube: 30pcs/Tube, 1800pcs/Ctn |

IMPORTANT NOTICE

Micro Commercial Components Corp. reserves the right to make changes without further notice to any product herein to make corrections, modifications, enhancements, improvements, or other changes. **Micro Commercial Components Corp.** does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights, nor the rights of others. The user of products in such applications shall assume all risks of such use and will agree to hold **Micro Commercial Components Corp.** and all the companies whose products are represented on our website, harmless against all damages. **Micro Commercial Components Corp.** products are sold subject to the general terms and conditions of commercial sale, as published at <https://www.mccsemi.com/Home/TermsAndConditions>.

LIFE SUPPORT

MCC's products are not authorized for use as critical components in life support devices or systems without the express written approval of Micro Commercial Components Corporation.

CUSTOMER AWARENESS

Counterfeiting of semiconductor parts is a growing problem in the industry. Micro Commercial Components (MCC) is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. MCC strongly encourages customers to purchase MCC parts either directly from MCC or from Authorized MCC Distributors who are listed by country on our web page cited below. Products customers buy either from MCC directly or from Authorized MCC Distributors are genuine parts, have full traceability, meet MCC's quality standards for handling and storage. **MCC will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources.** MCC is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.